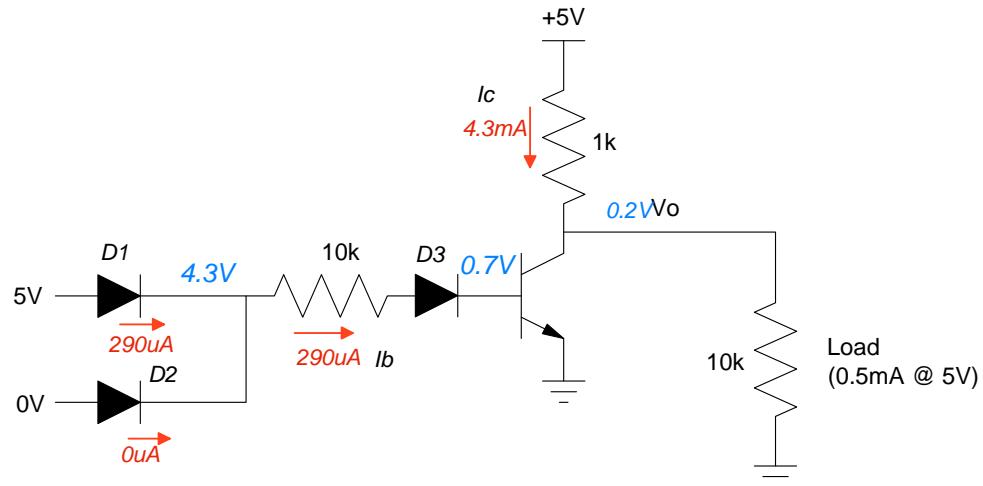


ECE 320 - Homework #7

DTL, TTL Logic. Due Monday, October 10th

DTL Logic:

- Determine the voltages and currents for the following DTL NOR gate:



Diode D1 is on, Diode D2 is off

$$I_b = \left(\frac{5V - 2.1V}{10k} \right) = 290\mu A$$

This allows up to 29mA to flow in the transistor

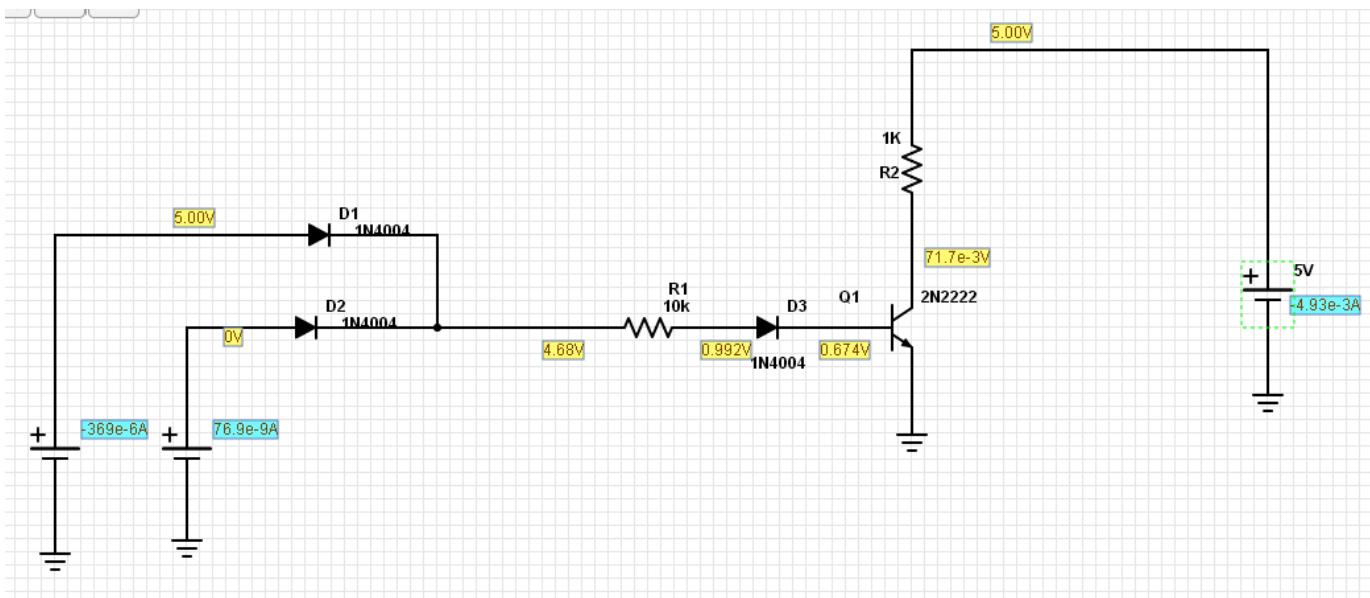
$$\beta I_b = 29.0mA$$

The maximum current in I_c is

$$\max(I_c) = \left(\frac{5V - 0.2V}{1k} \right) = 4.8mA < 29mA$$

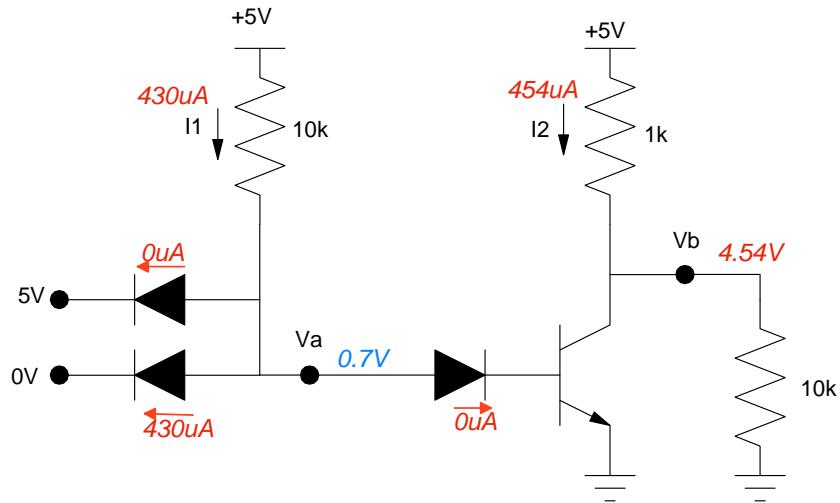
so the transistor is saturated.

2) Check your analysis with PartSim (or similar program)

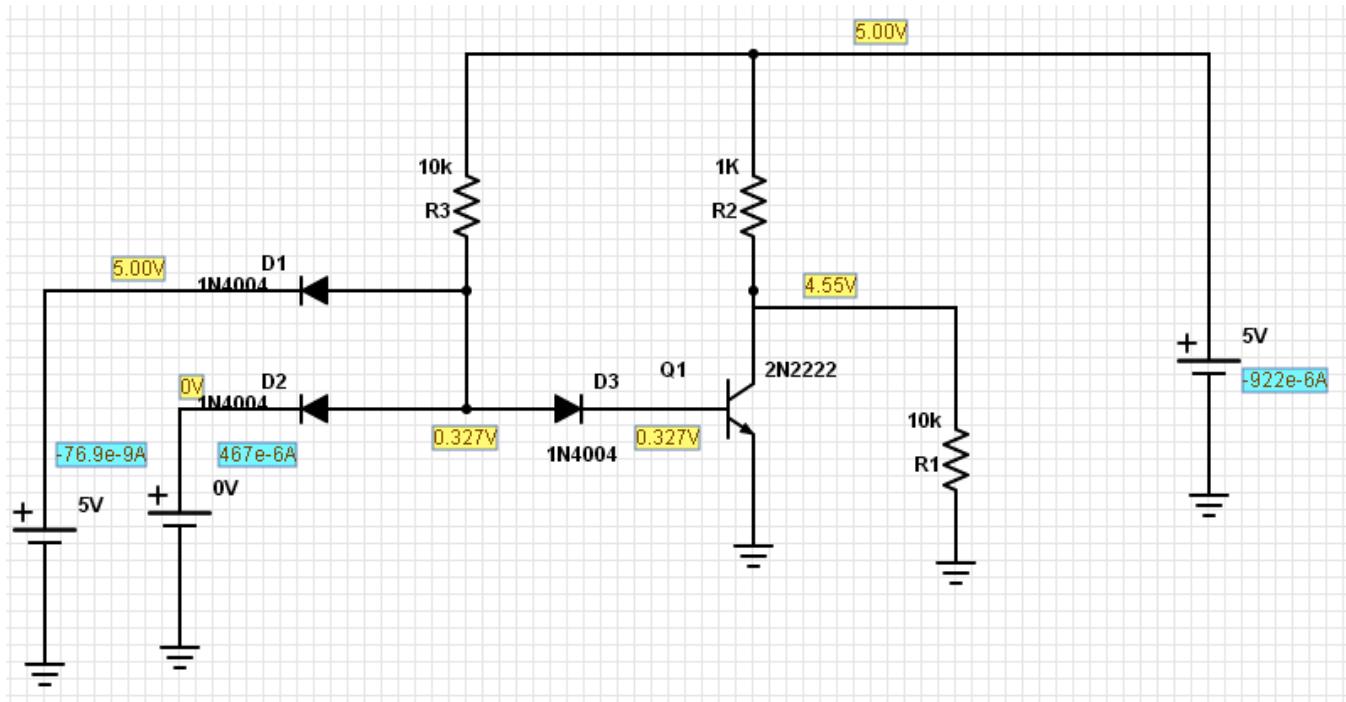


Parameter	Computed	PartSim
Id1	290uA	369uA
Id2	0mA	-0.076uA
Id3	290uA	369uA
Ic	4.8mA	4.93mA
Vc	200mV	71.7mV

3) Determine the voltages and currents for the following DTL NAND gate:



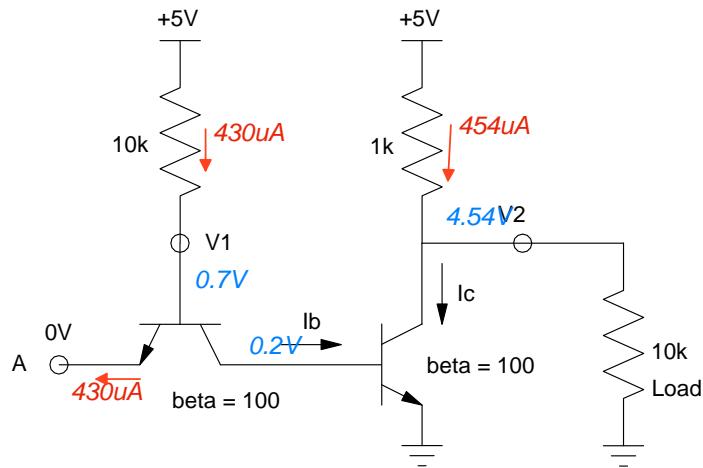
4) Check your analysis with PartSim (or similar program)



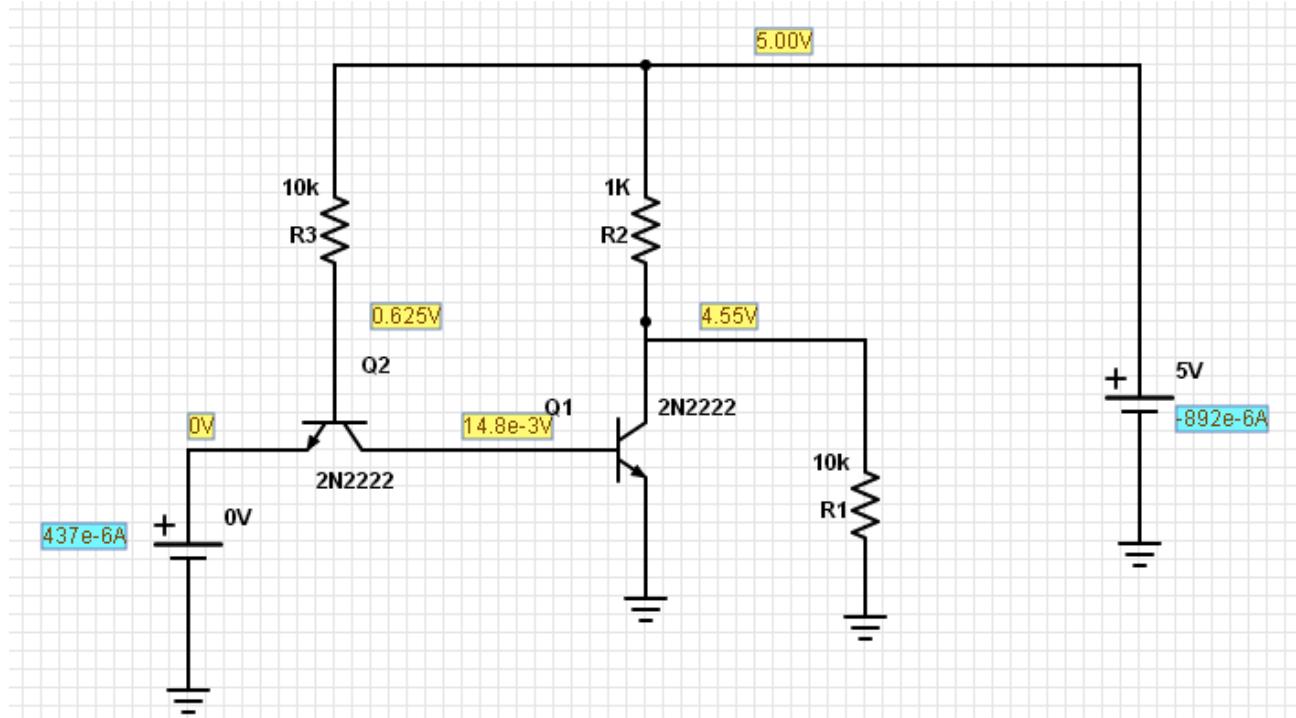
Parameter	Computed	PartSim
I _{d1}	0uA	-0.077uA
I _{d2}	430uA	467uA
I _{d3}	0uA	0uA
V _y	4.4V	4.55V

TTL Logic

5) Determine the voltages and currents for the following TTL inverter

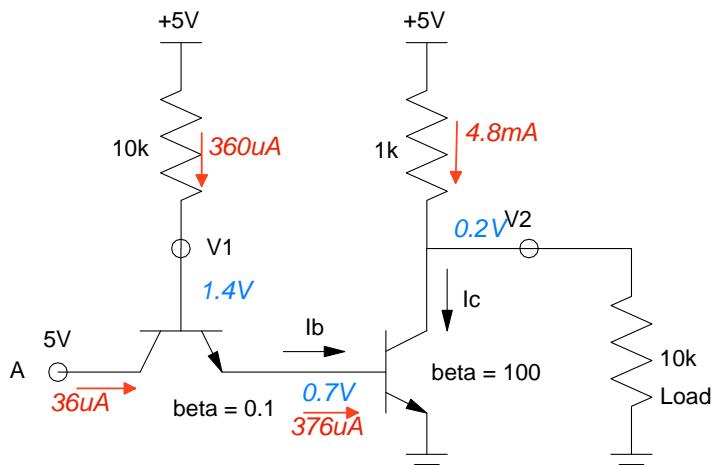


In PartSim

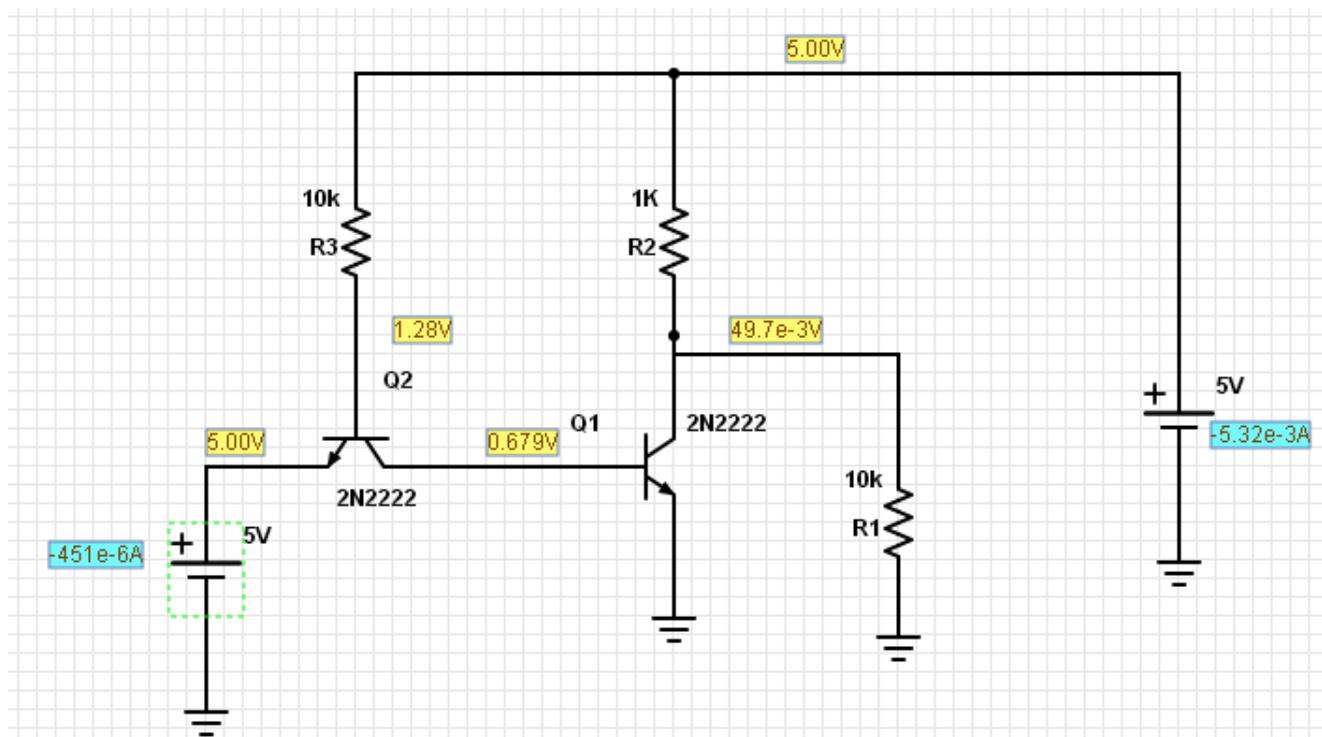


Parameter	Computed	PartSim
I_{in}	$430\mu A$	$437\mu A$
V_{b1}	$200mV$	$14.8mV$
V_{b2}	$700mV$	$625mV$
V_{c1}	$4.45V$	$4.55V$

Determine the voltages and currents for the following TTL inverter



In PartSim



Parameter	Computed	PartSim
I_{in}	36uA	451uA
V_{b1}	0.7V	0.679V
V_{b2}	1.4V	1.28V
V_{c1}	0.2V	0.0497V

Term Project:

Specify a device which uses two different circuits we cover in ECE 320.

7) Overall Requirements: Specify what the entire system does in terms of

- Inputs
- Outputs
- Relationship: How the inputs affect the outputs

8) Project Breakdown: Show how this device can be build using two different circuits covered in ECE 320. For each circuit, specify the

- Inputs
- Outputs
- Relationship: How the inputs affect the outputs